



IDS 9/24/03 , P. 1

(4 pages total)

LIST OF PUBLICATIONS CITED BY APPLICANT			<u>Atty Docket No.</u> 0553-0185.01		<u>Serial No.</u> Not Assigned	
			<u>Applicant</u> Mitsunori SAKAMA et al			
			<u>Filing Date</u> Herewith		<u>Group</u>	
U.S. PATENT DOCUMENTS						
*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB- CLASS	FILING DATE
	5,323,042	06/21/94	Matsumoto	257	57	11/13/92
	5,970,384	10/19/99	Yamazaki et al	438	795	08/02/95
	6,166,414	12/26/00	Miyazaki et al	257	369	08/25/99
	6,198,133 B1	03/06/01	Yamazaki et al	257	347	02/16/99
	6,281,552 B1	08/28/01	Kawasaki et al	257	350	03/22/00
	6,306,694 B1	10/23/01	Yamazaki et al	438	151	03/10/00
	6,399,988 B1	06/04/02	Yamazaki	257	344	03/22/00
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	JP 5-102483	04/23/93	Sharp Corp.	X	X	10/09/91
	JP 7-335900	12/22/95	Semiconductor Energy Lab Co. Ltd.	X		06/09/94
	JP 8-078329	03/22/96	Semiconductor Energy Lab Co. Ltd.	X		09/05/94
	JP 10-135468	05/22/98	Semiconductor Energy Lab Co. Ltd.	X		10/24/96
	JP 10-135469	05/22/98	Semiconductor Energy Lab Co. Ltd.	X		10/24/96

Examiner: J. MONDT

Date: 11/12/05



IDS 9/22/03, p.2

**OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS**

(Include name of author (in CAPITAL LETTERS), title of article or item (book, magazine, journal, serial, symposium, catalog, etc.) date, pages(s), volume-issue number(s), publisher, city and/or country where published).

*not considered (in breach of 1.98)*

- JH*
- 1) TERADA, H. et al, "Half V Switching Mode FLC," Proceedings of the 46<sup>th</sup> Applied Physics Association Lectures, 28p-V-8, p.1316, March, 1999.
  - 2) YOSHIHARA, T. et al, "Time Division Full Color LCD by Ferroelectric Liquid Crystal," EKISHO, vol. 3, no. 3, pp. 190-194, 1999.

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DATE CONSIDERED: 11/12/05

\*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP form. Draw line through citation if not in conformance and not considered. Include a copy of this form with the next communication to applicant.

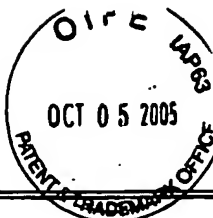
IDS 9/24/03, p. 3

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			<u>Filing Date</u> Herewith		<u>Group</u>	
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	5,640,067	06/17/97	Yamauchi et al	313	504	03/18/96
	5,643,826	07/01/97	Ohtani et al	437	88	10/25/94
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	JP 7-130652	05/19/95	Semiconductor Energy Lab Co. Ltd.	X		10/29/93
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	JP 10-092576	04/10/98	Cambridge Display Technology Ltd.	X		04/18/97
	JP 10-247735	09/14/98	Semiconductor Energy Lab Co. Ltd.	X		03/03/97

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IDS 9/24/03, p. 4

LIST OF PUBLICATIONS CITED BY APPLICANT		Atty. Docket No. 0553-0185.01		Serial No. Not Assigned		
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<i>[Signature]</i>	5,594,569	01/14/97	Konuma et al	349	122	07/20/94
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<i>[Signature]</i>	5) INUI, S. et al, "Thresholdless Antiferroelectricity in Liquid Crystals and its Application to Displays," J. Mater. Chem., vol. 6, no. 4, pp. 671-673, (1996).					
<i>[Signature]</i>	6) YOSHIDA, T. et al, "A Full-Color Thresholdless Antiferroelectric LCD Exhibiting Wide Viewing Angle with Fast Response Time," SID 97 Digest, pp. 841-844, (1997).					
<i>[Signature]</i>	7) FURUE, H. et al, "Characteristics and Driving Scheme of Polymer-Stabilized Monostable FLCs Exhibiting Fast Response Time and High Contrast Ratio with Gray-Scale Capability," SID 98 Digest, pp. 782-785, (1998).					
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IDS 10/5/05 (ip.)

LIST OF PUBLICATIONS CITED BY APPLICANT	<u>Atty. Docket No.</u> 0553-0185.01	<u>Serial No.</u> 10/669,284
	<u>Applicant</u> Mitsunori SAKAMA et al	
	<u>Filing Date</u> September 24, 2003	<u>Group</u> 2826

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	1) RABILLER, P. et al, "Electrical Properties of PECVD SiO <sub>2</sub> N <sub>2</sub> -H Prepared by Microwave Plasma," Conference Record of the 1988 IEEE International Symposium on Electrical Insulation, IEEE, pp. 149-152 (1988). 2) KAPOOR, V.J., "Review of Thin Oxynitride Dielectrics for Memory Device Technology," Journal of the Electrochemical Society, vo. 138, no. 3, pp. 657-666 (1991).
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